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Supplemental information

Paradoxical effects of posterior intralaminar thalamic calretinin neurons on hippocampal seizure via distinct downstream circuits

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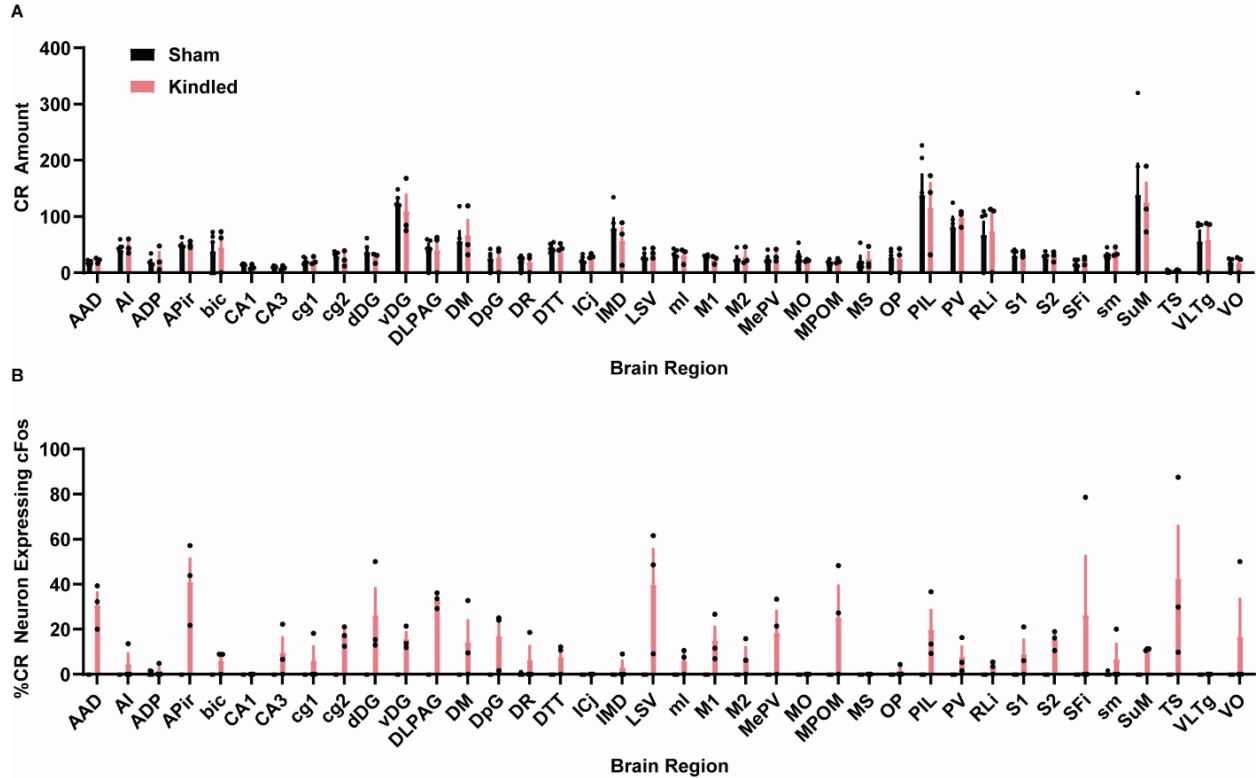


Figure S1 Activation of CR neurons in different brain regions after hippocampal seizure.

(A and B) Average number of CR neurons (A) and cFos⁺ CR neurons (B) in different brain regions of WT sham and kindling-induced epilepsy model (n = 5 for Sham group, n = 3 for Kindled group). Data are represented as mean ± SEM. AAD, anterior amygdaloid area (dorsal); AI, agranular insular cortex; ADP, anterodorsal preoptic nucleus; APir, amygdalopiriform transition area; bic, brachium of the inferior colliculus; CA1, field of CA1 of hippocampus; CA3, field of CA3 hippocampus; cg1, cingulate cortex area 1; cg2, cingulate cortex area 2; dDG, dorsal dentate gyrus; vDG, ventral dentate gyrus; DLPAG, dorsolateral periaqueductal gray; DM, dorsomedial hypothalamic nucleus; DpG, deep gray layer of the superior colliculus; DR, dorsal raphe nucleus; DTT, dorsal tenia tecta; ICj, islands of Calleja; IMD, intermediodorsal thalamic nucleus; LSV, lateral septal nucleus (ventral); ml, medial lemniscus; M1, primary motor cortex; M2, secondary motor cortex; MePV, medial amygdaloid nucleus (posteroventral); MO, medial orbital cortex. MPOM, medial preoptic nucleus; MS, medial septal nucleus; OP, optic nerve layer of the superior colliculus; PIL, posterior intralaminar thalamic nucleus; PV, paraventricular thalamic nucleus; RLi, rostral linear nucleus of the raphe; S1, primary somatosensory cortex; S2, secondary somatosensory cortex; SFi, septofimbrial nucleus; sm, stria medullaris of the thalamus; SuM, supramammillary nucleus; TS, triangular septal nucleus; VLTg, ventrolateral tegmental area; VO, ventral orbital cortex. **Related to Figure 1.**

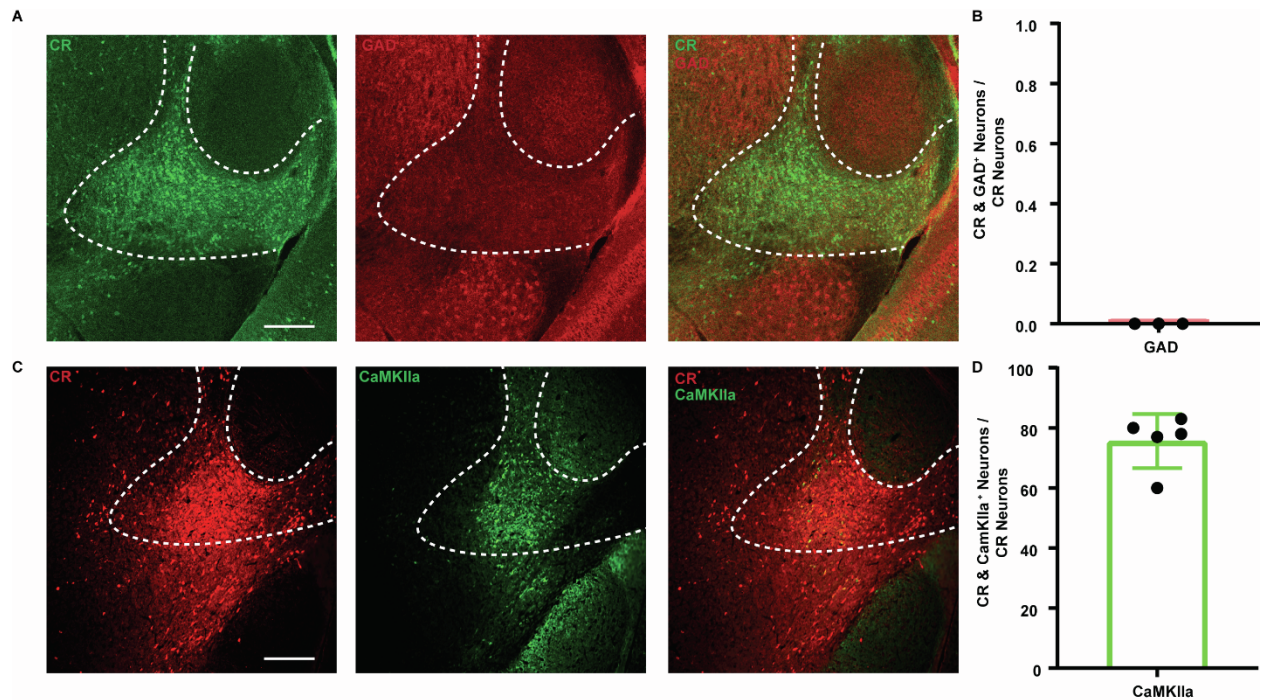


Figure S2 CR neurons in the PIL are glutamatergic neurons.

(A) Representative immunostaining images of CR neurons in the PIL region (green), GAD65/67 (red), and overlap of CR and GAD65/67 (Scale Bar: 200 μ m).

(B) Statistical data for colocalization of CR neurons and GAD overlap (n=3).

(C) Representative immunostaining images of CR neurons in the PIL region (red), CaMKII α (green), and overlap of PIL and CaMKII α (Scale Bar: 200 μ m).

(D) Statistical data for the percentage CR neurons that expressed CaMKII α (n=5).

Data are represented as mean \pm SEM. **Related to Figure 4.**

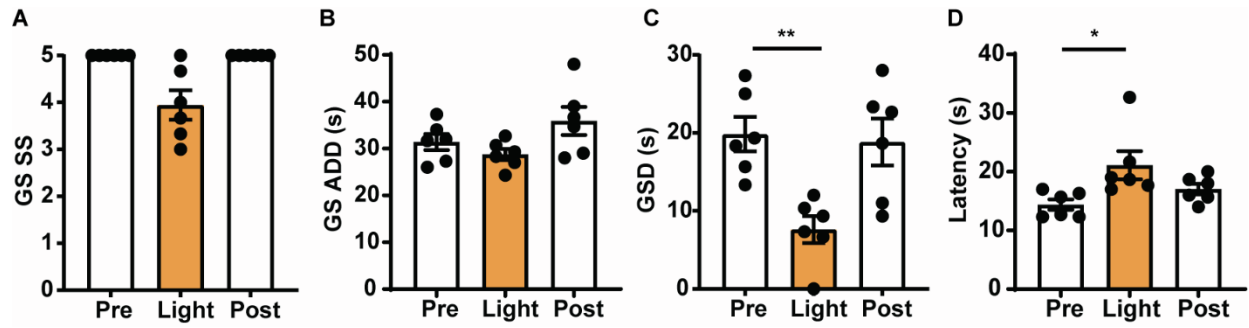


Figure S3 Inhibition of PIL-LA CR circuit alleviates the severity of GS in fully kindled state. (A-D) Effects of optogenetic inhibition of PIL-LA CR projections on seizure stage (SS, A), after-discharge duration (ADD, B), GS duration (GSD, C), and latency to GS (D) during hippocampal kindled seizure. (n = 6) * $P < 0.05$, ** $P < 0.01$, one-way ANOVA. Data are represented as mean \pm SEM. Related to Figure 5.

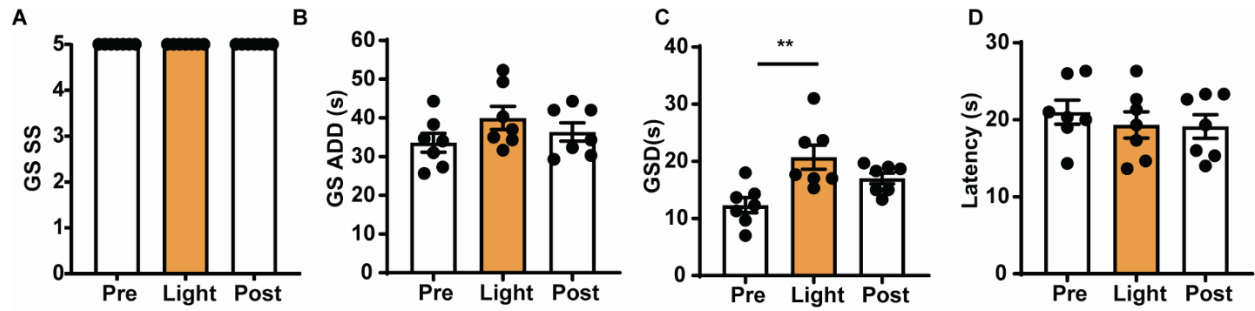


Figure S4 Inhibition of PIL-ZI CR circuit aggravates the severity of GS in fully kindled state. (A-D) Effects of optogenetic inhibition of PIL-ZI CR projections on seizure stage (SS, A), after-discharge duration (ADD, B), GS duration (GSD, C), and latency to GS (D) during hippocampal kindled seizure. (n = 7) **P<0.01, one-way ANOVA. Data are represented as mean \pm SEM. **Related to Figure 6.**

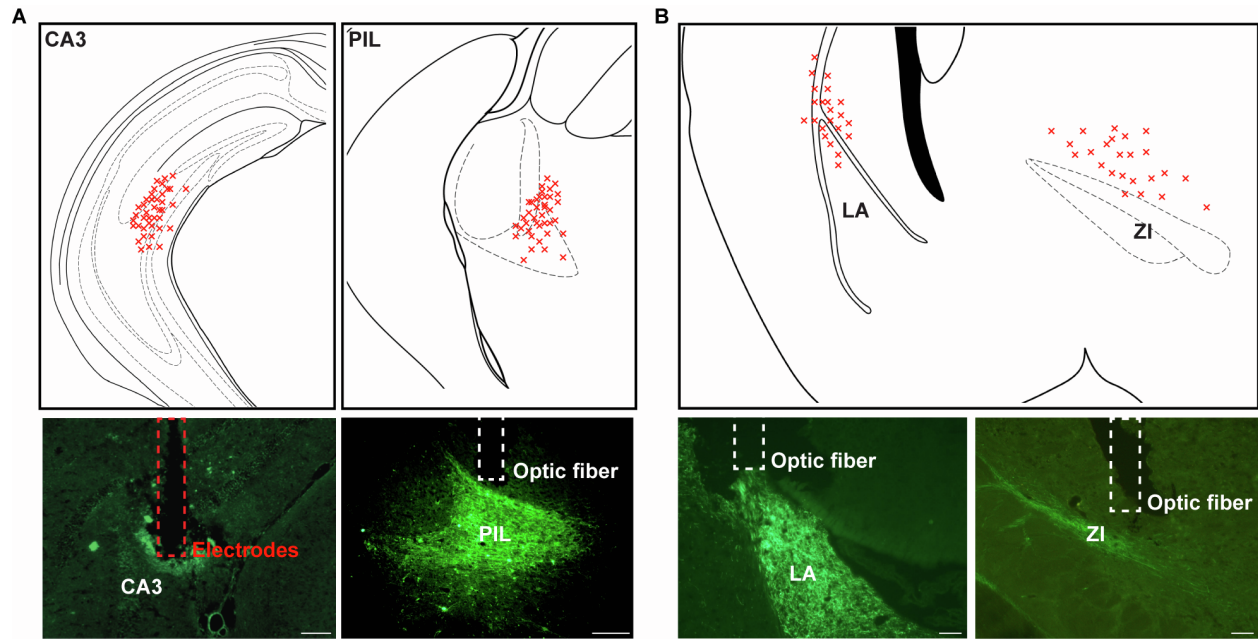


Figure S5 Mapping the location of electrodes and optic fibers in optogenetic experiment.

(A) Above, mapping the location of kindling electrodes in the CA3 and optic fibers in the PIL in optogenetic experiment in Figures 2 and 3. Below, representative images for the location of kindling electrodes in the CA3 and optic fibers in the PIL. **Related to Figure 2 and 3.**

(B) Above, mapping the optic fibers in the LA and ZI in optogenetic experiment in Figures 5 and 6. Below, representative images for the location of optic fibers in the LA and ZI. **Related to Figure 5 and 6.**

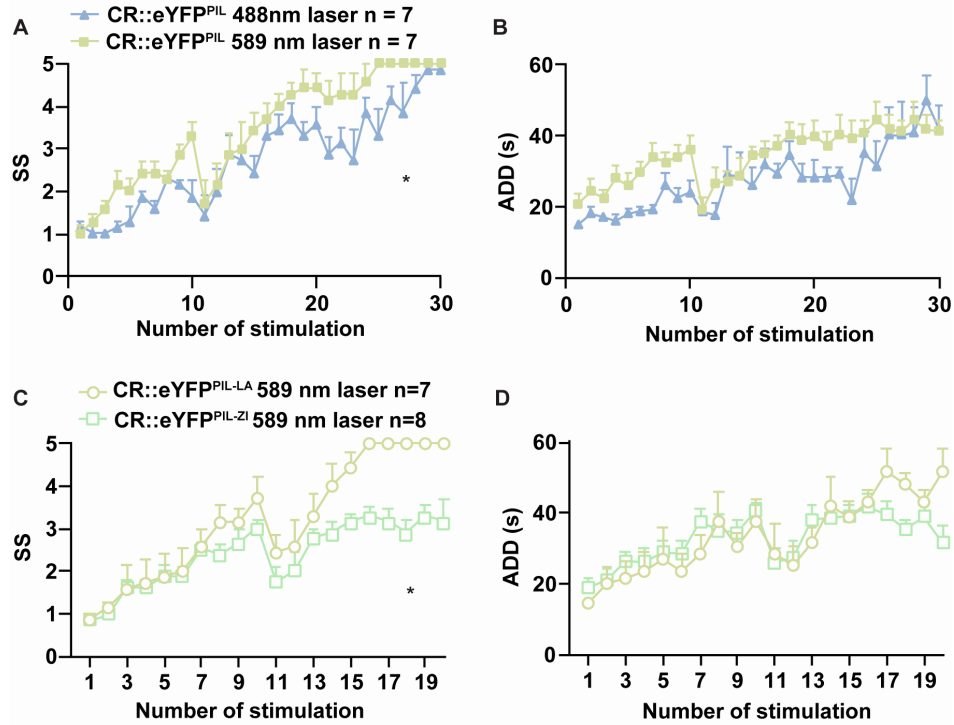


Figure S6 Different epileptogenic susceptibility of control groups in optogenetic experiment. (A and B) The development of seizure stage (SS, A) and after-discharge duration (ADD, B) in control groups of optogenetics experiment in Figures 2 and 3. * $P < 0.05$, two-way ANOVA with repeated measures. Data are represented as mean \pm SEM. **Related to Figure 2 and 3.** (C and D) The development of SS (C) and ADD (D) in control groups of optogenetics experiment in Figures 5 and 6. * $P < 0.05$, two-way ANOVA with repeated measures. Data are represented as mean \pm SEM. **Related to Figure 5 and 6.**